

# AAP Gen 7 (TO-240AA) Power Modules Schottky Rectifier, 200 A



AAP Gen 7 (TO-240AA)

| PRIMARY CHARACTERISTICS  |                            |  |  |
|--------------------------|----------------------------|--|--|
| I <sub>F(AV)</sub> 200 A |                            |  |  |
| $V_{R}$                  | 150 V                      |  |  |
| Package                  | AAP Gen 7 (TO-240AA)       |  |  |
| Circuit configuration    | Two diodes doubler circuit |  |  |

#### **MECHANICAL DESCRIPTION**

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- UL approved file E78996



- Low thermal resistance
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **BENEFITS**

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- · High surge capability
- · Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION / APPLICATIONS**

The VS-VSKDS409/150 Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |   |                        |    |  |  |
|-----------------------------------|---|------------------------|----|--|--|
| SYMBOL                            | CHARACTERISTICS                               | CHARACTERISTICS VALUES |    |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                          | 200                    | A  |  |  |
| V <sub>RRM</sub>                  |   | 150                    | V  |  |  |
| I <sub>FSM</sub>                  | $t_p = 5 \mu s sine$                          | 20 000                 | A  |  |  |
| V <sub>F</sub>                    | 200 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.85                   | V  |  |  |
| TJ                                | Range   | -55 to +175            | °C |  |  |

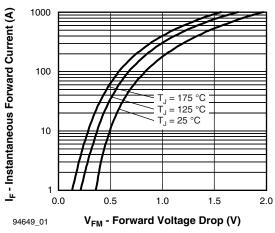
| VOLTAGE RATINGS                     |           |                 |       |  |  |
|-------------------------------------|-----------|-----------------|-------|--|--|
| PARAMETER                           | SYMBOL    | VS-VSKDS409/150 | UNITS |  |  |
| Maximum DC reverse voltage          | $V_{R}$   | 150             | V     |  |  |
| Maximum static peak reverse voltage | $V_{RRM}$ | 150             | V     |  |  |



| ABSOLUTE MAXIMUM RATINGS             |                    |  |  |        |       |
|--------------------------------------|--------------------|--|--|--------|-------|
| PARAMETER                            | SYMBOL             | TEST CONDITIONS  |  | VALUES | UNITS |
| Maximum average forward current      | I <sub>F(AV)</sub> | 50 % duty cycle at T <sub>C</sub> = 105 °C, rectangular waveform   |  | 200    |       |
| Maximum peak one cycle               | I <sub>FSM</sub>   | 5 μs sine or 3 μs rect. pulse  | Following any rated load condition and with rated V <sub>RRM</sub> applied | 20 000 | Α     |
| non-repetitive surge current         |                    | 10 ms sine or 6 ms rect. pulse   |  | 2300   |       |
| Non-repetitive avalanche energy      | E <sub>AS</sub>    | $T_J = 25  ^{\circ}\text{C},  I_{AS} = 1.8  \text{A},  L = 10  \text{mH}$  |  | 15     | mJ    |
| Repetitive avalanche current         | I <sub>AR</sub>    | Current decaying linearly to zero in 1 $\mu$ s<br>Frequency limited by $T_J$ maximum $V_A = 1.5$ x $V_R$ typical |  | 1      | А     |
| Maximum dynamic peak reverse voltage | V <sub>AV</sub>    | $T_J = 25 ^{\circ}\text{C},  I_{AS} = 1.8  \text{A},  L = 10  \text{mH}$   |  | 170    | V     |

| ELECTRICAL SPECIFICATIONS  |                  |  |                                       |                            |       |
|--|------------------|--|---------------------------------------|----------------------------|-------|
| PARAMETER  | SYMBOL           | TEST CONDITIONS  |                                       | VALUES                     | UNITS |
| Marian marianta da | V                | 200 A  | T <sub>J</sub> = 25 °C                | 1.03                       | V     |
|  |                  | 400 A  |                                       | 1.33                       |       |
| Maximum forward voltage drop   | $V_{FM}$         | 200 A  | T <sub>J</sub> = 125 °C               | 0.85                       |       |
|  |                  | 400 A  |                                       | 1.13                       |       |
| Marian and an Indiana and  | I <sub>RM</sub>  | T <sub>J</sub> = 25 °C                                       | V <sub>R</sub> = Rated V <sub>R</sub> | 6                          | mA    |
| Maximum reverse leakage current  |                  | T <sub>J</sub> = 125 °C                                      |                                       | 85                         | IIIA  |
| Maximum junction capacitance   | C <sub>T</sub>   | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C |                                       | 6000                       | pF    |
| Typical series inductance  | Ls               | Measured lead to lead 5 mm from package body                 |                                       | 5.0                        | nH    |
| Maximum voltage rate of change   | dV/dt            | Rated V <sub>R</sub>   |                                       | 10 000                     | V/µs  |
| Maximum RMS insulation voltage   | V <sub>INS</sub> | 50 Hz  |                                       | 3000 (1 min)<br>3600 (1 s) | V     |

| THERMAL - MECHANICAL SPECIFICATIONS                     |             |                                   |  |             |          |
|---|-------------|-----------------------------------|--|-------------|----------|
| PARAMETER   |             | SYMBOL                            | TEST CONDITIONS  | VALUES      | UNITS    |
| Maximum junction and storage temperature range          | e           | T <sub>J</sub> , T <sub>Stg</sub> |  | -55 to +175 | °C       |
| Maximum thermal resistance, junction to case per leg    |             | R <sub>thJC</sub>                 | DC operation   | 0.32        | °C/W     |
| Typical thermal resistance, case to heatsink per module |             | R <sub>thCS</sub>                 |  | 0.1         | C/VV     |
| Approximate weight                                      |             |                                   |  | 75          | g        |
| Approximate weight                                      |             |                                   |  | 2.7         | oz.      |
| Mounting torque ± 10 %                                  | to heatsink |                                   | A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the | 4           | Nm       |
|   | busbar      |                                   | spread of the compound.  | 3           | INIII    |
| Case style  |             |                                   | JEDEC®   | TO-240AA co | mpatible |





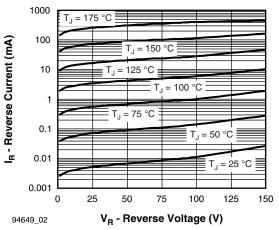


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

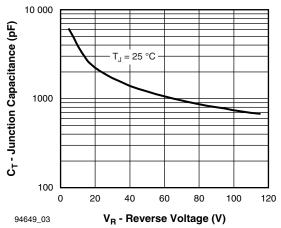


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

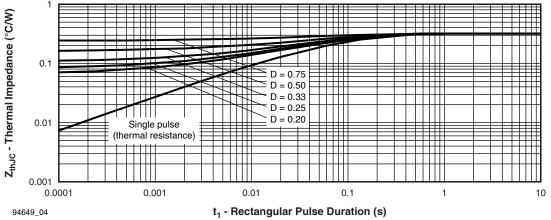


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Diode)

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## Vishay Semiconductors

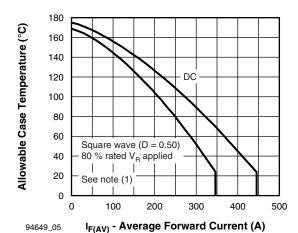


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

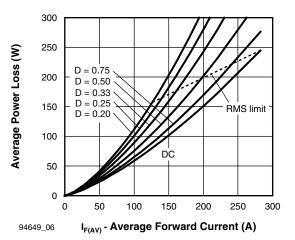


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

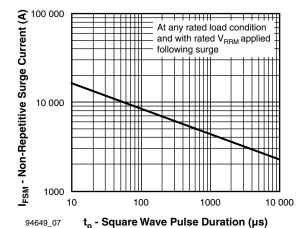


Fig. 7 - Maximum Non-Repetitive Surge Current

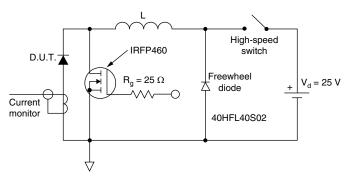
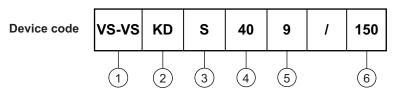


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6);$  $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

#### **ORDERING INFORMATION TABLE**



1 - Vishay Semiconductors product

2 - Circuit configuration:

KD = ADD-A-PAK - 2 diodes doubler circuit

3 - S = Schottky diode

4 - Average current rating (40 = 400 A) (1)

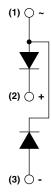
5 - Product silicon identification

6 - Voltage rating (150 = 150 V)

#### Note

(1) For KD configuration average current rating per module is 200 A

#### **CIRCUIT CONFIGURATION**



| LINKS TO RELATED DOCUMENTS |                          |  |  |
|----------------------------|--------------------------|--|--|
| Dimensions                 | www.vishay.com/doc?95369 |  |  |



## **ADD-A-PAK Generation VII - Diode**

#### **DIMENSIONS** in millimeters (inches)





## **Legal Disclaimer Notice**

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